

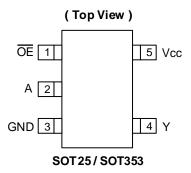


SINGLE BUFFER GATE WITH 3-STATE OUTPUT

Description

The 74AHC1G125Q is an automotive compliant single non-inverting buffer/bus driver with a 3-state output. The output enters a high impedance state when a HIGH-level is applied to the output enable (\overline{OE}) pin. The device is designed for operation with a power supply range of 2.0V to 5.5V.

Pin Assignments



Features

- Grade 1 Ambient Temperature Operation: -40°C to +125°C
- Supply Voltage Range from 2.0V to 5.5V
- ±8mA Output Drive at 4.5V
- CMOS Low-Power Consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time
- Inputs Not Limited by V_{CC}
- Balanced Propagation Delays
- Balanced Drive Capability
- ESD Protection Tested per AEC-Q100
- Exceeds 2000-V Human Body Model (AEC-Q100-002)
- Exceeds 1000-V Charged Device Model (AEC-Q100-011)
- Latch-Up Exceeds 100mA (AEC-Q100-004)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The 74AHC1G125Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Applications

- General Purpose Logic
- · Wide Array of Products, such as:
 - Automotive Applications within Grade 1 Temperature Range
 - Industrial Computing/Controls/Automation
 - High Reliability Networking/Communications
 - Industrial/Agricultural Equipment

Notes:

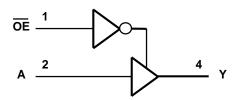
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Name	Description
ŌE	Output Enable
Α	Data Input
GND	Ground
Υ	Data Output
Vcc	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
ŌE	Α	Υ
L	Н	Н
L	L	L
Н	X	Z

Absolute Maximum Ratings (Notes 4 & 5)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
Vcc	Supply Voltage Range	-0.5 to 6.5	V
Vı	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage Applied to Output in High or Low State	-0.5 to Vcc + 0.5	V
lıĸ	Input Clamp Current V _I < 0	-20	mA
lok	Output Clamp Current (Vo < 0 or Vo > Vcc)	±20	mA
lo	Continuous Output Current (Vo = 0 to Vcc)	±25	mA
Icc	Continuous Current Through Vcc	75	mA
Ignd	Continuous Current Through GND	-75	mA
TJ	Operating Junction Temperature	-40 to +150	°C
Tstg	Storage Temperature	-65 to +150	°C
PD	Total Power Dissipation (Note 6)	250	mW

Notes:

- 4. Stresses beyond the absolute maximum can result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.
- 5. Forcing the maximum allowed voltage could cause a condition exceeding the maximum current or conversely forcing the maximum current could cause a condition exceeding the maximum voltage. The ratings of both current and voltage must be maintained within the controlled range.
- 6. This will need to be derated at higher operating temperatures to prevent exceeding maximum T_J. Refer to package thermal characteristics section.



Recommended Operating Conditions (Note 7)

Symbol	Р	arameter	Min	Max	Unit
Vcc	Operating Voltage	_	2	5.5	V
		Vcc = 2V	1.5	_	
V _{IH}	V _{IH} High-Level Input Voltage	V _{CC} = 3V	2.1	_	V
		Vcc = 5.5V	3.85	_	
		V _{CC} = 2V	_	0.5	
VIL	Low-Level Input Voltage	Vcc = 3V	_	0.9	V
		V _{CC} = 5.5V	_	1.65	
Vı	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V _{CC}	V
		Vcc = 2V	_	-50	μA
Іон	High-Level Output Current	$V_{CC} = 3.3V \pm 0.3V$	_	-4	
		$V_{CC} = 5V \pm 0.5V$	_	-8	mA
		V _{CC} = 2V	_	50	μΑ
loL	Low-Level Output Current	$VCC = 3.3V \pm 0.3V$	_	4	
		$V_{CC} = 5V \pm 0.5V$	_	8	mA
		$V_{CC} = 3.3V \pm 0.3V$	_	100	
Δt/ΔV	Input Transition Rise or Fall Rate	$V_{CC} = 5V \pm 0.5V$	_	20	ns/V
TA	Operating Free-Air Temperature	_	-40	+125	°C

Note:

Electrical Characteristics (All typical values are at V_{CC} = 3.3V, T_A = +25°C.)

0	B	Table On well the same	V		+25°C		-40°C to	o +85°C	-40°C to	+125°C	1124					
Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Min	Max	Min	Max	Unit					
		M M M	2V	1.9	2	_	1.9	_	1.9	_						
		V _I = V _{IH} or V _{IL}	3V	2.9	3	_	2.9	_	2.9	_						
	Lligh Lovel	$I_{OH} = -50\mu A$	4.5V	4.4	4.5	_	4.4	_	4.4	_						
Vон	High Level Output Voltage	VI = VIH OR VIL IOH = -4mA	3V	2.58	_	_ 2.48 _ 2.40 _	V									
		VI = VIH OR VIL IOH = -8mA	4.5V	3.94	_	_	3.8	_	3.70	_						
		\\.\.\\.\.\\.\.\\.\\.\\\\\\\\\\\\\\\\\	2V	_	_	0.1	_	0.1		0.1						
		$V_{I} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu A$	3V		_	0.1	_	0.1	_	0.1						
	Law Lavel Output		4.5V	_	_	0.1	_	0.1		0.1						
V _{OL}	Voltage	Low Level Output Voltage		3V	_	_	0.36	_	0.44	_	0.55	V				
										4.5V	1	_	0.36	_	0.44	-
loz	Z State Leakage Current	$V_1 = 5.5V \text{ or GND}$ $V_0 = 0 \text{ to } 5.5V$	5.5V	l	_	0.25	-	2.5	ı	10	μΑ					
lı	Input Current	V _I = 5.5V or GND	0 to 5.5V	1	_	±0.1	_	±1	ı	±2	μΑ					
Icc	Supply Current	V _I = 5.5V or GND Io = 0	5.5V	_	_	1	_	10	_	40	μА					
Cı	Input Capacitance	V _I = V _{CC} or GND	5.5V		2.0	10	_	10	_	10	pF					

^{7.} Unused inputs should be held at V_{CC} or Ground.



Package Characteristics

Symbol	Parameter	Package	Test Conditions	Min	Тур	Max	Unit
0	Thermal Resistance	SOT25	Nata 0	-	184	_	°C/W
θ JA	Junction-to-Ambient	SOT353	Note 8	_	385	_	
	Thermal Resistance	SOT25	Nata 0	_	62	_	0000
θЈС	Junction-to-Case	SOT353	Note 8	1	164	_	°C/W

Note:

Switching Characteristics

 $Vcc = 3.3V \pm 0.3V$ (See Figure 1)

Parameter From		То	Test		+25°C		-40°C t	o +85°C	-40°C to	+125°C	Unit
Parameter	(Input)	(Output)	Conditions	Min	Тур	Max	Min	Max	Min	Max	Offic
4	۸	V	C _L = 15pF	1.0	4.7	8.0	1.0	9.5	1.0	11.5	ns
ιPD	t _{PD} A	r	C _L = 50pF	1.0	6.6	11.5	1.0	13.0	1.0	14.5	ns
4	, ===	V	C _L = 15pF	1.0	5.0	8.0	1.0	9.5	1.0	11.5	ns
t _{EN}	OE	Ţ	C _L = 50pF	1.0	6.9	11.5	1.0	13.0	1.0	14.5	ns
4-10	-	=	$C_L = 15pF$	1.0	6.0	9.7	1.0	11.5	1.0	12.5	ns
tois	OE	Ť	C _L = 50pF	1.0	8.3	13.2	1.0	15.0	1.0	16.5	ns

Vcc = 5V ± 0.5V (See Figure 1)

Parameter	From	То	Test		+25°C		-40°C t	o +85°C	-40°C to	+125°C	Unit
Faranietei	(Input)	(Output)	Conditions	Min	Тур	Max	Min	Max	Min	Max	Ollit
4	۸	V	C _L = 15pF	1.0	3.4	5.5	1.0	6.5	1.0	7.0	ns
ιPD	t _{PD} A Y	Ţ	C _L = 50pF	1.0	4.8	7.5	1.0	8.5	1.0	9.5	ns
4	. =	>	$C_L = 15pF$	1.0	3.6	5.1	1.0	6.0	1.0	6.5	ns
tEN	OE	Ţ	C _L = 50pF	1.0	4.9	7.5	1.0	8.5	1.0	9.5	ns
4	<u> </u>	V	$C_L = 15pF$	1.0	4.1	6.8	1.0	8.0	1.0	8.5	ns
tois	OE	Ť	C _L = 50pF	1.0	5.7	8.8	1.0	10.0	1.0	11.0	ns

Operating Characteristics

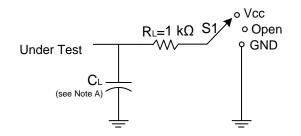
 $T_A = +25$ °C

Parameter		Test Conditions	Vcc = 5V Typ	Unit
CPD	Power Dissipation Capacitance	f = 1MHz No Load	10	pF

^{8.} Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

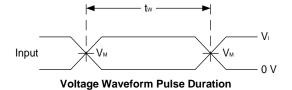


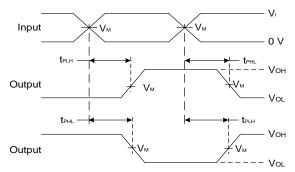
Measurement Information



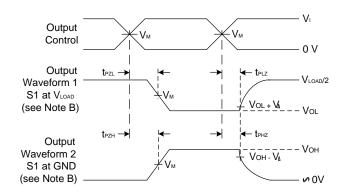
Test	S1
t _{PLH} /t _{PHL}	Open
tplz/tpzl	V _{LOAD}
tpHZ/tpZH	GND

V	In	puts	V	0	VA	
Vcc	VI	t _R /t _F	V _M	CL	V Δ	
3.3V±0.3V	Vcc	≤3ns	V _{CC} /2	15pF	0.3V	
5V±0.5V	Vcc	≤3ns	V _{CC} /2	15pF	0.3V	
3.3V±0.3V	Vcc	≤3ns	V _{CC} /2	50pF	0.3V	
5V±0.5V	Vcc	≤3ns	V _{CC} /2	50pF	0.3V	





Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs



Voltage Waveform Enable and Disable Times Low and High Level Enabling

Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

B. All pulses are supplied at pulse repetition rate ≤ 1MHz.

C. Inputs are measured separately one transition per measurement.

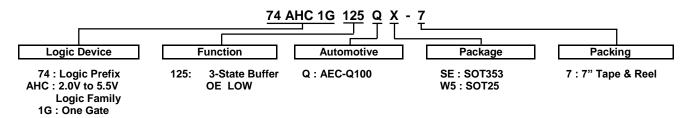
D. t_{PLZ} and t_{PHZ} are the same as t_{DIS} .

E. t_{PZL} and t_{PZH} are the same as t_{EN} .

F. t_{PLH} and t_{PHL} are the same as $t_{\text{PD}}.$



Ordering Information (Note 9)



Part Number	Package	Package	Package Size	7" Tape	and Reel
Fait Number	Code	(Notes 10 & 11)	Fackage Size	Quantity	Part Number Suffix
74AHC1G125QSE-7	SE	SOT353	2.15mm × 2.1mm × 1.1mm 0.65mm lead pitch	3000/Tape & Reel	-7
74AHC1G125QW5-7	W5	SOT25	3.0 mm \times 2.8 mm \times 1.2 mm 0.95 mm lead pitch	3000/Tape & Reel	-7

Notes:

For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.
 Pad layout as shown in Diodes Incorporated's package outline PDFs, which can be found on our website at http://www.diodes.com/package-outlines.html.
 The taping orientation is located on our website at https://www.diodes.com/assets/Packaging-Support-Docs/ap02007.pdf.

Marking Information

(Top View)

XXX YWX 2

XXX: Identification Code

: Year 0~9 : Week: A~Z 1~26 week

a~z 27~52 week z represents week 52 and 53

X : A~ Z: Internal Code

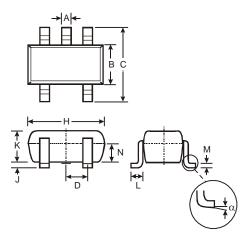
SOT 25 / SOT 353

Part Number	Package	Identification Code
74AHC1G125QW5-7	SOT25	YYQ
74AHC1G125QSE-7	SOT353	YYQ



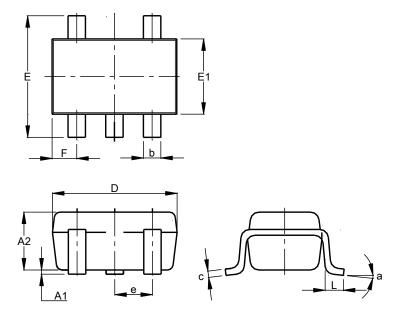
Package Outline Dimensions

(1) Package Type: SOT25



SOT25				
Dim	Min	Max	Тур	
Α	0.35	0.50	0.38	
В	1.50	1.70	1.60	
С	2.70	3.00	2.80	
D	-	-	0.95	
Н	2.90	3.10	3.00	
J	0.013	0.10	0.05	
K	1.00	1.30	1.10	
L	0.35	0.55	0.40	
M	0.10	0.20	0.15	
N	0.70	0.80	0.75	
α	0°	8°	-	
All Dimensions in mm				

(2) Package Type: SOT353



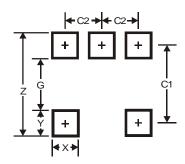
SOT353					
Dim	Min	Max	Тур		
A1	0.00	0.10	0.05		
A2	0.90	1.00	0.95		
b	0.10	0.30	0.25		
С	0.10	0.22	0.11		
D	1.80	2.20	2.15		
Е	2.00	2.20	2.10		
E1	1.15	1.35	1.30		
е	0.650 BSC				
F	0.40	0.45	0.425		
L	0.25	0.40	0.30		
а	0°	8°			
All Dimensions in mm					



Suggested Pad Layout

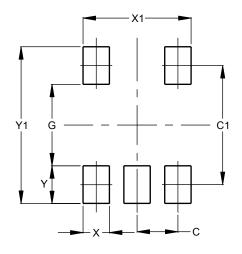
Please see http://www.diodes.com/package-outlines.html for the latest version.

(1) Package Type: SOT25



Dimensions	Value
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

(2) Package Type: SOT353



Dimensions	Value (in mm)
С	0.650
C1	1.900
G	1.300
Х	0.420
X1	1.720
Υ	0.600
Y1	2.500

Mechanical Data

SOT25

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.0158 grams (Approximate)

SOT353

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.0064 grams (Approximate)



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